## NSN 5961-00-295-5757

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-295-5757 **Inclosure Material:** Glass **Overall Length:** 0.375 inches **Terminal Length:** 1.125 inches **Overall Diameter:** 0.210 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage and 600.0 working peak reverse voltage and 800.0 nonrepetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 3.00 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 170.0 degrees celsius case **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: